



## SMT GaAs HBT MMIC DIVIDE-BY-2, DC - 8 GHz

### Typical Applications

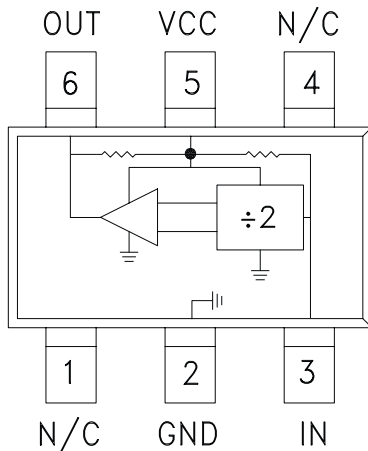
Prescaler for DC to C Band PLL Applications:

- UNII, Point-to-Point & VSAT Radios
- 802.11a & HiperLAN WLAN
- Fiber Optic
- Cellular / 3G Infrastructure

### Features

- Ultra Low SSB Phase Noise: -148 dBc/Hz
- Single-Ended I/O's
- Output Power: -3 to -9 dBm
- Single DC Supply: +3V @ 42 mA
- 9 mm<sup>2</sup> Ultra Small Package: SOT26

### Functional Diagram



### General Description

The HMC432(E) is a low noise Divide-by-2 Static Divider utilizing InGaP GaAs HBT technology in ultra small surface mount SOT26 plastic packages. This device operates from DC (with a square wave input) to 8 GHz input frequency with a single +3V DC supply. Single-ended inputs and outputs reduce component count and cost. The low additive SSB phase noise of -148 dBc/Hz at 100 kHz offset helps the user maintain good system noise performance.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , 50 Ohm System, $V_{CC} = +3V$

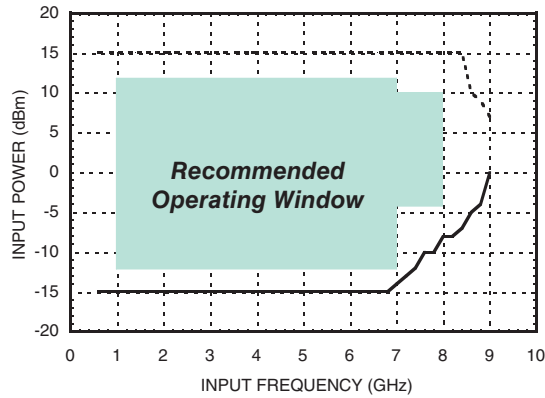
Parameter	Conditions	Min.	Typ.	Max.	Units
Maximum Input Frequency		8	8.5		GHz
Minimum Input Frequency	Sine Wave Input. [1]		0.2		GHz
Input Power Range	Fin= 1 to 7 GHz Fin= 7 to 8 GHz	-12 -4		+12 +10	dBm
Output Power	Fin= 4 GHz Fin= 8 GHz	-6 -12	-3 -9		dBm dBm
Reverse Leakage	RF Output Terminated, Fin= 4 GHz, Pin= 0 dBm		-30		dBm
SSB Phase Noise (100 kHz offset)	Pin= 0 dBm, Fin= 4 GHz		-148		dBc/Hz
Output Transition Time	Pin= 0 dBm, Fout= 882 MHz		145		ps
Supply Current (Icc)	Vcc= 3.0 V		42	56	mA

1. Divider will operate down to DC for square-wave input signal.

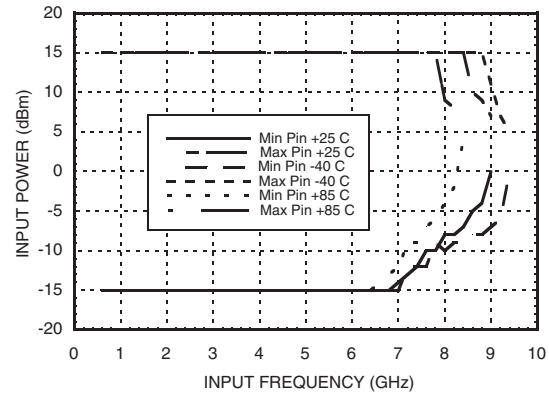


**SMT GaAs HBT MMIC  
DIVIDE-BY-2, DC - 8 GHz**

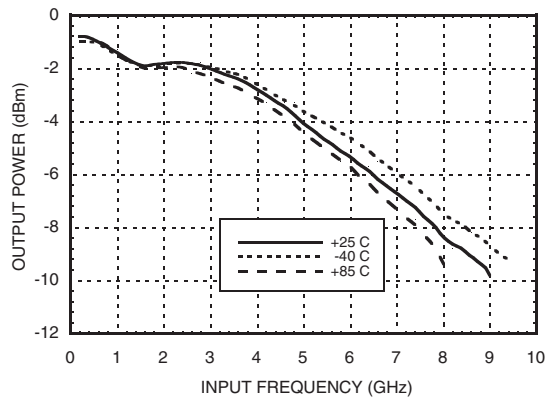
**Input Sensitivity Window,  $T = 25\text{ }^{\circ}\text{C}$**



**Input Sensitivity Window vs. Temperature**

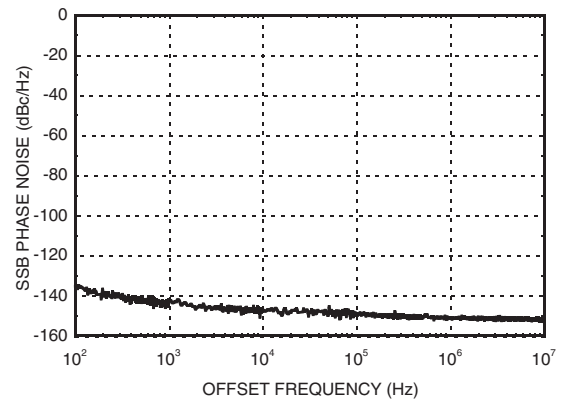


**Output Power vs. Temperature**



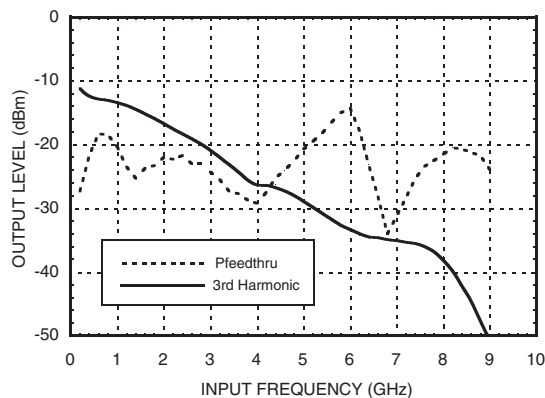
**SSB Phase Noise**

**Performance,  $P_{in} = 0\text{ dBm}$ ,  $T = 25\text{ }^{\circ}\text{C}$**

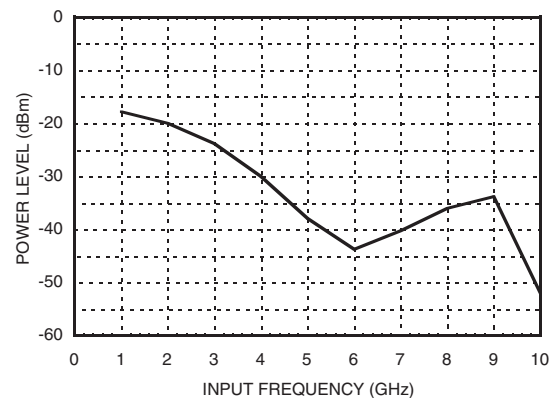


**Output Harmonic**

**Content,  $P_{in} = 0\text{ dBm}$ ,  $T = 25\text{ }^{\circ}\text{C}$**



**Reverse Leakage,  $P_{in} = 0\text{ dBm}$ ,  $T = 25\text{ }^{\circ}\text{C}$**



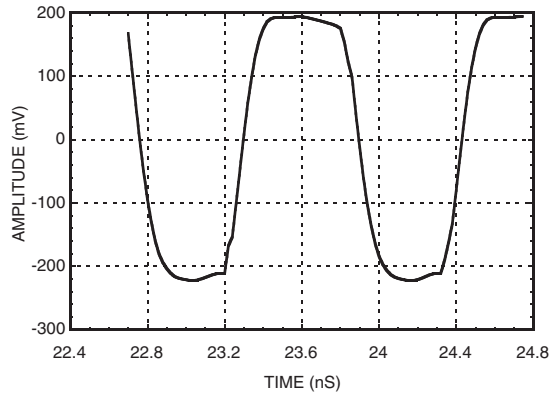
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com) Application Support: Phone: 1-800-ANALOG-D



## SMT GaAs HBT MMIC DIVIDE-BY-2, DC - 8 GHz

**Output Voltage Waveform,**  
*Pin= 0 dBm, Fout= 882 MHz, T= 25 °C*



### Absolute Maximum Ratings

RF Input Power (Vcc = +3V)	15 dBm
Nominal +3V Supply to GND	-0.3V to 3.5V
Max Peak Flow Temperature	260 °C
Storage Temperature	-65 to +125 °C
ESD Sensitivity (HBM)	150 V

### Reliability Information

Junction Temperature to Maintain 1 Million Hour MTTF	135 °C
Nominal Junction Temperature (T = 85 °C)	99 °C
Thermal Resistance (Junction to GND Paddle, 3V Supply)	108 °C/W
Operating Temperature	-40 to +85 °C

DC blocking capacitors are required at RF input and RF output ports. Choose value for lowest frequency of operation.

### Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)
2.70	34
3.00	42
3.30	50

Note: Divider will operate over full voltage range shown above

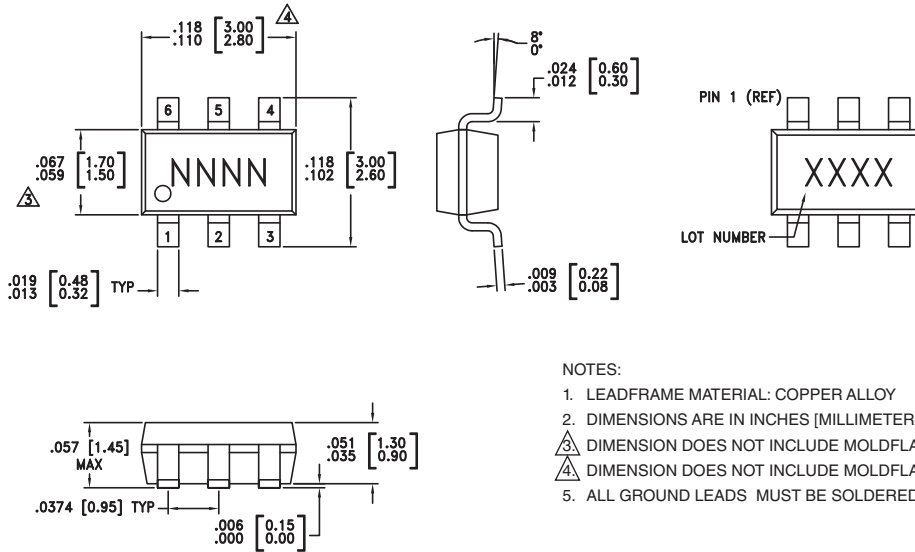


**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**



## SMT GaAs HBT MMIC DIVIDE-BY-2, DC - 8 GHz

### Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
5. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.

### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[3]</sup>
HMC432	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	H432 XXXX
HMC432E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	432E XXXX

- [1] Max peak reflow temperature of 235 °C  
 [2] Max peak reflow temperature of 260 °C  
 [3] 4-Digit lot number XXXX

### Pin Description

Pin Number	Function	Description	Interface Schematic
1, 4	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2	GND	Pin must connect to RF/DC ground.	
3	IN	RF input must be DC blocked.	

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106  
 Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com)  
 Application Support: Phone: 1-800-ANALOG-D

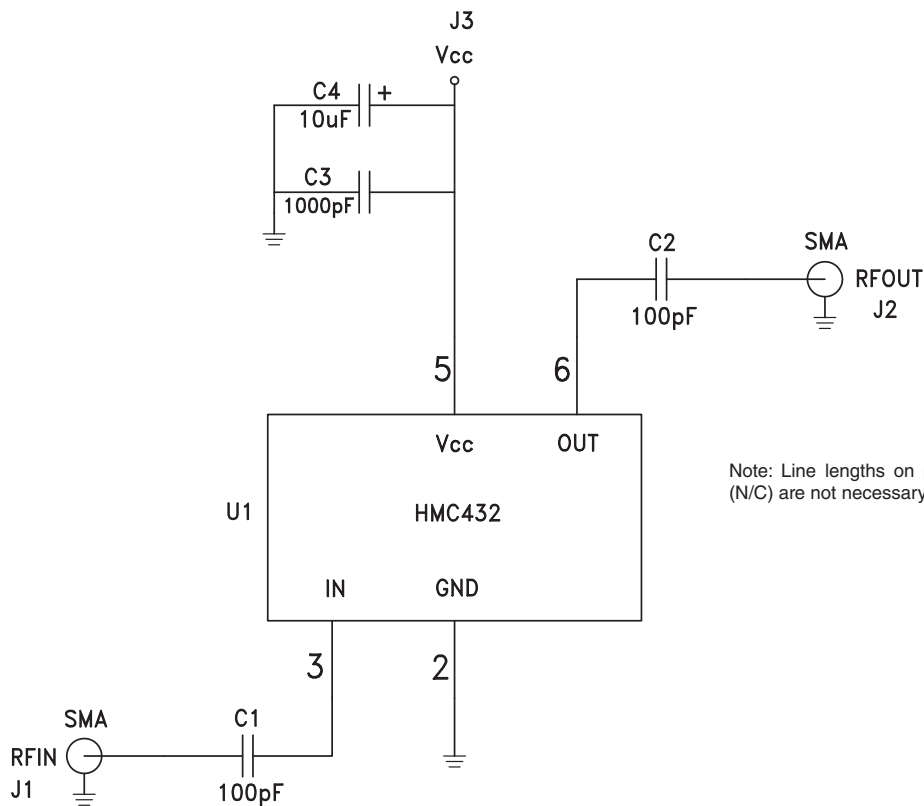


**SMT GaAs HBT MMIC  
DIVIDE-BY-2, DC - 8 GHz**

**Pin Description (Continued)**

Pin Number	Function	Description	Interface Schematic
5	Vcc	Supply voltage 3V ± 0.3V.	
6	OUT	Divided output must be DC blocked.	

**Application Circuit**



Note: Line lengths on pins 1 & 4 (N/C) are not necessary.

Note:

DC blocking capacitor values (C1, C2) and DC decoupling capacitor values (C3, C4) are chosen for lowest frequency of operation.